

Fractional Minima in the Conductivity of the Quantum–Hall–System under Microwaves

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We analyse theoretically the conductivity of a quantum Hall system exposed to microwave radiation. We find that whenever microwave frequency and cyclotron frequency are commensurate, there is a *resonance* in the longitudinal conductivity. This resonance has the form of the derivative of a Lorentz function; precisely at the center of the resonance, the microwave induced conductivity vanishes. Between the resonances there are maxima and minima, the depths and precise positions of which depend on the microwave amplitude and the scattering rate of the impurities. We demonstrate the existence of these resonances by a microscopic, analytical calculation of the conductivity in lowest order in the microwave intensity and show here that the conductivity is independent of the microwave polarization, linear or circular. We then discuss the general case and predict minima in the longitudinal conductivity corresponding to fractional values of the microwave frequency divided by the cyclotron frequency.

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The discovery of new zero–resistance states [1] in the quantum Hall system under microwave irradiation stimulated a lot of attention, both experimental, c.f. Refs. [2, 3, 4, 5, 6, 7, 8] and theoretical, c.f. Refs. [9, 10, 11] and references therein. As in the original quantum Hall experiment, one finds regions of vanishing longitudinal resistivity as the magnetic field varies, but these are not accompanied by plateaux in the Hall resistivity, instead one sees a classical straight line. Moreover, the regions of vanishing ρ_{xx} are now labeled by the ratio ε of the microwave frequency ω_f to the cyclotron frequency ω_c , $\varepsilon = \omega_f/\omega_c$, while in the case of the quantum Hall effect, they are classified by the filling factor ν . There are different theoretical explanations of these experimental findings. An oscillatory dependence of the conductivity on ω_f was already predicted in early theoretical work by Ryzhii et al. [12, 13]. In Ref. [9] the radiation–induced zeros (minima) in the resistivity are seen as the consequence of photo–excited disorder–scattered electrons contributing to the resistivity in an oscillatory manner due to the impurity–broadened energy structure of the Landau levels. On the other hand, in Refs. [4, 11] an oscillating non-equilibrium distribution function is invoked. Both quite different approaches yield negative resistivities in some regions of ε . Finally, Ref. [10] complements the picture with the observation that in regions of negative resistivity a phase–separation occurs which leads to zero–resistance states. In spite of all this work, no final consensus about the microscopic origin of the features occurring in the electronic transport seems to have emerged.

This situation calls for a careful re–analysis of the microscopic derivation of the microwave–induced conductivity, in particular concerning the approximations used. Such an attempt is made in the present paper. We are lead to a new view on the mechanism responsible for the structures in the conductivity, as well as the prediction of minima near fractional values of ε in very clean samples. We set ourselves a modest goal: we want to analyze the *onset* of the effect. Thus, we can expand in the electric field E_f of the microwave. That, and the use of

a simple model for the impurity scattering makes it possible to carry out an analytical treatment that enables us to detect the dependence of the conductivity on its parameters – up to the final evaluation. In the first and major part of this paper we analyze the origin of the structures in the conductivity up to second order in E_f , and at the end, we make the prediction of minima (zeros) near fractional values of ε which appear in higher order in E_f . We extend and modify the work presented in Ref. [9] in three essential ways: First, we do not employ the rotating wave approximation. That enables us to study arbitrary microwave polarization, and it will be essential for our prediction. Second, we couple the microwave field to the velocity, rather than to the position. We can thus avoid considering vertex corrections in the case of isotropic impurity scattering. Third, we use a simple model for the life time of the disordered electronic states. That enables an analytical treatment.

We consider electrons moving in the x-y plane in a magnetic field $B\hat{e}_z$ (given by its vector potential $\vec{A} = xB\hat{e}_y$), and in a microwave field with the electric field polarized in the x-direction (given by $\vec{A}_f(t) = \frac{-cE_f}{\omega_f} \sin(\omega_f t) \hat{e}_x$), and in an impurity potential $V_{imp}(\vec{x})$, i.e. the Hamiltonian

$$H = \frac{1}{2m} \left(\vec{p} - \frac{e}{c} \vec{A} - \frac{e}{c} \vec{A}_f(t) \right)^2 + V_{imp}(\vec{x}). \quad (1)$$

The average over $V_{imp}(\vec{x})$ will be discussed below; all the other symbols not mentioned so far have their standard meaning. Note that the coupling to the microwave field is different from that in Ref. [9]: (i) *both* terms $\exp(\mp i\omega_f t)$, absorption and emission of photons, accompany a transition to the next higher Landau level (matrix element of $v_x + iv_y$ with $\vec{v} = (\vec{p} - \frac{e}{c} \vec{A})/m$) and the same holds for the Hermitean conjugate process. This corresponds to arbitrary linear polarization of the microwave field. (ii) the coupling to the microwave field is through the vector potential (of the form $v_x(A_f)_x$). Consequently, we need to include a number of diamagnetic terms; in this way we can avoid considering vertex corrections due to

the impurities (ladder diagrams) as is discussed below.

The quantity we want to calculate is the conductivity σ . Since the microwaves introduce a time dependent term into the Hamiltonian, we will get currents depending on time as $\exp(-i(j\omega_f + \omega)t)$ for the external electric field $\vec{E}_{ext} \propto \exp(-i\omega t)$ for any integer j . However, in the experiment, one measures the d.c. current ($j\omega_f + \omega \rightarrow 0$). Therefore, we must neglect all terms in the current which oscillate in time. In perturbation theory in E_f , we must keep only contributions with the same number of incoming ($\exp(-i\omega_f t)$) and outgoing ($\exp(+i\omega_f t)$) photon lines. Since we have a

non-equilibrium problem, we employ the Keldysh technique [14] and use the notations of Ref. [15]. We apply the standard method of linear response under an external electric field produced by the vector potential $c/(i\omega)\vec{E}_{ext}e^{-i\omega t}$ and write the conductivity as $\sigma_{\alpha\beta}(\omega) = \sigma_{\alpha\beta}^{(0)}(\omega) + \sigma_{\alpha\beta}^{(2)}(\omega) + \mathcal{O}(E_f^4)$ where $\sigma_{\alpha\beta}^{(0)}$ is the conductivity without microwaves and $\sigma_{\alpha\beta}^{(2)}$ is quadratic in E_f . Due to the A_f^2 -term in H , we get a number of “diamagnetic terms”. We order the result for $\sigma_{\alpha\beta}^{(2)}$ w.r. to the number of Green’s functions G , which are calculated in absence of the microwave field:

$$\begin{aligned} \sigma_{\alpha\beta}^{(2)}(\omega) = & \frac{e^2}{2\pi} \left(\frac{el_BE_f}{2\omega_f} \right)^2 \frac{1}{\omega} \int \frac{d\epsilon}{2\pi} \left[\text{Sp} \left\{ v_\alpha \sigma_- G(\epsilon) v_x \sigma_z G(\epsilon - \omega_f) v_x \sigma_z G(\epsilon) v_\beta \sigma_z G(\epsilon - \omega) \right\} \right. \\ & + \frac{1}{2} \text{Sp} \left\{ v_\alpha \sigma_- G(\epsilon) v_x \sigma_z G(\epsilon - \omega_f) v_\beta \sigma_z G(\epsilon - \omega - \omega_f) v_x \sigma_z G(\epsilon - \omega) \right\} \Big] \\ & + \frac{e^2}{2\pi} \left(\frac{el_BE_f}{2\omega_f} \right)^2 \frac{1}{\omega} \int \frac{d\epsilon}{2\pi} \left[\text{Sp} \left\{ v_\alpha \sigma_- G(\epsilon) v_x \sigma_z G(\epsilon - \omega_f) \sigma_z G(\epsilon - \omega) \right\} \delta_{\beta x} \right. \\ & + \text{Sp} \left\{ \sigma_- G(\epsilon) v_\beta \sigma_z G(\epsilon - \omega) v_x \sigma_z G(\epsilon - \omega - \omega_f) \right\} \delta_{\alpha x} \\ & + \frac{1}{2} \text{Sp} \left\{ \sigma_- G(\epsilon) v_x \sigma_z G(\epsilon - \omega_f) v_x \sigma_z G(\epsilon) \right\} \delta_{\alpha\beta} \\ & + \frac{1}{2} \text{Sp} \left\{ v_\alpha \sigma_- G(\epsilon) \sigma_z G(\epsilon) v_\beta \sigma_z G(\epsilon - \omega) \right\} \Big] \\ & + \frac{e^2}{2\pi} \left(\frac{el_BE_f}{2\omega_f} \right)^2 \frac{1}{\omega} \int \frac{d\epsilon}{2\pi} \left[\frac{1}{2} \text{Sp} \left\{ \sigma_- G(\epsilon) \sigma_z G(\epsilon - \omega_f - \omega) \right\} \delta_{\alpha x} \delta_{\beta x} + \frac{1}{2} \text{Sp} \left\{ \sigma_- G(\epsilon) \sigma_z G(\epsilon) \right\} \delta_{\alpha\beta} \right] \\ & + (\omega_f \rightarrow -\omega_f); + (\omega \rightarrow -\omega, \text{ c.c.}) \end{aligned} \quad (2)$$

Here, G is a matrix in the 2×2 Keldysh-space, as well as a matrix in the quantum numbers (n and k) of the states for $V_{imp} = 0$. G still contains the impurity potential V_{imp} and the disorder average is implied. The Pauli-matrices σ_i act in the Keldysh-space, the components of the current $\vec{v} = (\vec{p} - e/c\vec{A})/m$ in the space of the quantum numbers n and k . All frequencies, or energies, have been scaled by ω_c and are dimensionless, as is the velocity, since it is scaled by $1/(ml_B)$ where $l_B = \sqrt{c/|eB|}$ is the magnetic length. The prefactor of the conductivity is the natural unit of conductance $e^2/(2\pi\hbar)$ ($\hbar$ is restored; everywhere else, we use units with $\hbar = 1$). The dimensionless quantity

$$I_f = \left(\frac{el_BE_f}{2\omega_f} \right)^2 \quad (3)$$

describes the intensity of the microwaves. Its relation to the parameter I used in Ref. [9] contains the fine-structure constant and the ratio $\varepsilon = \omega_f/\omega_c$, $I_f = 2\pi e^2/(\hbar c) \omega_f/\omega_c I$. Now we proceed with the evaluation of $\sigma_{\alpha\beta}^{(2)}$. Using the equation of motion for G (and its adjoint) we find

$$G(\omega)v_\beta \sigma_z G(\omega) = G(\omega)i[H, x_\beta]\sigma_z G(\omega) = i[G(\omega), x_\beta] \quad (4)$$

Using this relation and $G^\dagger(\omega) = -\sigma_x G(\omega)\sigma_x$, one can convince oneself that there is no $1/\omega$ -term in $\sigma_{\alpha\beta}^{(2)}$ as $\omega \rightarrow 0$. This

is a consequence of gauge invariance. We perform the d.c.-limit by taking the derivative w.r. to ω and specialize to the case of the diagonal conductivity, $\beta = \alpha$. We now perform the trace in Keldysh space: after a rotation of the Keldysh matrices (see Ref. [15])

$$G = \frac{1}{2} \begin{pmatrix} SS1 & SS1 \\ SS-1 & SS1 \end{pmatrix} \begin{pmatrix} 0 & G_A \\ G_R & F \end{pmatrix} \begin{pmatrix} SS1 & SS1 \\ SS-1 & SS1 \end{pmatrix}^T \quad (5)$$

everything depends on the retarded and advanced Greens functions G_R and G_A only, since the Keldysh function F (related to the “lesser” Green’s function $G^<$) is given by $F(\omega) = [1 - 2f(\omega)] [G_R(\omega) - G_A(\omega)]$ where $f(\omega)$ denotes the Fermi function.

Now we want to discuss the impurity average. Before the average, the Green’s functions have the form

$$G_R(\omega) = \frac{1}{\omega - H_0 - V_{imp} + i0} \quad (6)$$

For a particle in two dimensions and a transverse magnetic field there is no dominating class of impurity diagrams that one could sum up to obtain the self energy. Therefore, we take as a phenomenological model for the impurity averaged Green’s functions the expression

$$G_R(\omega) = \frac{1}{\omega - H_0 + i/(2\tau)} \quad (7)$$

Here, the lifetime τ enters as a phenomenological parameter that we fit to the level broadening in the absence of microwaves, $E_f = 0$. We do not intend to calculate τ from a microscopic impurity model. Note that τ does not depend on the Landau level; as it will turn out, only Landau levels near the Fermi surface will enter, and as the chemical potential $\mu \approx 60\omega_f$, we can safely drop this dependence. Note also that the impurity averaged Green's functions become diagonal in the quantum numbers n and k and independent of k (translational invariance).

Next we discuss vertex corrections. For the “non-crossing approximation” in the disorder average [16] it is well-known that one needs to consider the “ladder”-type diagrams in the conductivity in order to have a conserved approximation. But for an isotropic scattering model, these ladders do not contribute at *current* vertices. So we take isotropic scattering, and that enables us to disregard vertex corrections. Note that this would fail at vertices with *position* operators.

At this point, we give an estimate of the maximum microwave intensity for which perturbation theory in lowest order is still applicable. The level distance is ω_c , the transition matrix element $\sqrt{n}\omega_c \frac{eE_f l_B}{2\omega_f}$, hence $nI_f^{\max} < 1$. Here, n is the number of the Landau level at the Fermi energy. There is a more stringent criterion: Calculating the change of the imaginary part of the self energy in second order perturbation theory in E_f and demanding that it be smaller than $1/\tau$, we get

$$n I_f^{\max} \frac{\omega_c^2}{(\omega_f - \omega_c)^2 + (\frac{1}{2\tau})^2} < 1, \quad (\omega_f \approx \omega_c). \quad (8)$$

In the worst case, at the resonance $\omega_f = \omega_c$, we have $n I_f^{\max} < (2\omega_c\tau)^{-2}$, much stronger than the criterion above. We want to evaluate the formula for the conductivity in the parameter regime

$$1/\tau < \omega_c \approx \omega_f < T < \mu \quad (9)$$

that corresponds to the experimental conditions; T is the temperature and $\mu \approx 60\omega_f$. The evaluation of the trace in the Keldysh space then leads to expressions of the form $\int d\epsilon [f(\epsilon - \omega_f) - f(\epsilon)]$ (or $\omega_f \rightarrow \omega$). Thus, strictly speaking, the conductivity is *not* a Fermi surface quantity; and this is rather obvious in the presence of microwaves. But since

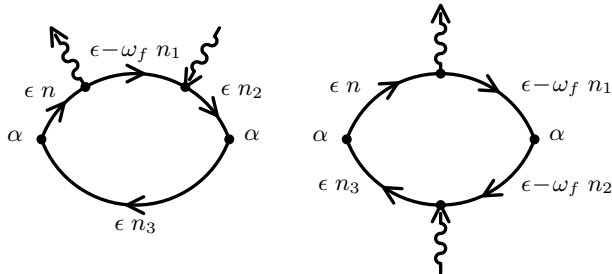


FIG. 1: Diagrams corresponding to the terms with four Green's functions in Eq. (10)

$\omega_f \ll \mu$, only states close to the Fermi surface enter and we can approximate $[f(\epsilon - \omega_f) - f(\epsilon)] \simeq -\omega_f f'(\epsilon)$. We thus get

$$\begin{aligned} \sigma_{\alpha\alpha}^{(2)}(0) \simeq & \frac{e^2}{2\pi} I_f \int \frac{d\epsilon}{2\pi} (-) f'(\epsilon) \\ & \left[-\text{Sp} \left\{ v_\alpha G_R v_x G_R(\epsilon - \omega_f) v_x G_R v_\alpha [G_R - G_A] \right\} \right. \\ & + \omega_f \text{Sp} \left\{ v_\alpha G_R v_x [G_R - G_A] (\epsilon - \omega_f) v_x G_A v_\alpha \partial_\epsilon G_A \right\} \\ & - \frac{1}{2} \text{Sp} \left\{ v_\alpha G_R v_x G_R(\epsilon - \omega_f) v_\alpha G_R(\epsilon - \omega_f) v_x G_R \right\} \\ & + \frac{1}{2} \text{Sp} \left\{ v_\alpha G_R(\epsilon - \omega_f) v_x G_R v_\alpha G_A v_x G_A(\epsilon - \omega_f) \right\} \\ & - \omega_f \text{Sp} \left\{ v_\alpha G_R v_x G_A(\epsilon - \omega_f) v_\alpha \partial_\epsilon [G_A(\epsilon - \omega_f) v_x G_A] \right\} \\ & \left. - \frac{1}{2} \text{Sp} \left\{ v_\alpha G_R G_R v_\alpha [G_R - G_A] \right\} \right] \\ & + (\omega_f \rightarrow -\omega_f); + (\text{c.c.}) \end{aligned} \quad (10)$$

Here, we omit the argument ϵ at the Green's functions $G_{R,A} \equiv G_{R,A}(\epsilon)$ for the sake of brevity. In Eq. (10), we have dropped several expressions of the type $[G_R - G_A](\epsilon) G_R(\epsilon - \omega_f) + (\omega_f \rightarrow -\omega_f)$ with two Green's functions with different energy dependence but without current operator in between. Such terms vanish before the impurity average ($\propto \delta(\omega_f)$).

It remains to evaluate the integral over ϵ and the trace over the Landau level quantum numbers in Eq. (10). We denote these quantum numbers by n, n_1, n_2 , and n_3 (see Fig. 1). Then, due to the current vertices between the Green's functions, there are only six combinations $\mathcal{C}$ ($n_1 = n \pm 1$, etc.) for n_1, n_2 , and n_3 which contribute to the trace for a given n . The integral over ϵ and the sum on n can be evaluated numerically for arbitrary temperature. For $T = 0$, we see strong Shubnikov-de Haas oscillations in $\sigma_{\alpha\alpha}^{(2)}$. As we are interested in the regime $\omega_c < T$, we use the Poisson summation formula and keep only its first term. Technically, that corresponds to replacing the sum over n by an integration over n . The lower limit of the integration is moved from 0 to $-\infty$, since the main contribution to the integral comes from $n \sim \mu/\omega_f$; that is correct in leading order in $\mu/\omega_f \rightarrow \infty$. The indefinite integral over n is then easily performed by contour integration and the SdH oscillations disappear. Finally, we have to perform the sum over the six possibilities $\mathcal{C}$ of the quantum numbers n_i . This requires some care: The expression corresponding to the left diagram in Fig. 1 for $n_2 = n$ contains a self energy insertion, which must be summed up. It then yields a correction to the single particle energy as well as to the life time. In the parameter range considered here such corrections are small and will be neglected. We write the conductivity as

$$\sigma_{\alpha\alpha}^{(0)}(0) + \sigma_{\alpha\alpha}^{(2)}(0) \simeq \sigma_{\alpha\alpha}^{(0)}(0) \left[1 + I_f \frac{\mu}{\omega_c} s \left(\frac{\omega_f}{\omega_c}, \frac{1}{\omega_c T} \right) \right] \quad (11)$$

Note that the matrix elements $(v_\alpha)_{n,n+1} \propto \sqrt{n}$ always appear in two pairs in Eq. (10), and therefore, the maximum power of n in the numerator is n^2 , i.e., after the contour integration, the maximum power of μ will be μ^1 (since $\sigma_{\alpha\alpha}^{(0)}(0) \propto \mu$). It can be shown that there is no linear order in μ in $\sigma_{\alpha\alpha}^{(2)}(0)$ and we

omit lower orders for $\mu/\omega_f \sim 60 \gg 1$. The evaluation of the function $s(\varepsilon, \delta)$ is straightforward; s has the form $s(\varepsilon, \delta) = p(\varepsilon, \delta)/q(\varepsilon, \delta)$ with

$$q(\varepsilon, \delta) = [(2 + \varepsilon)^2 + \delta^2]^2 [(2 - \varepsilon)^2 + \delta^2]^2 (\varepsilon^2 + \delta^2)^2 (1 + \delta^2) [(1 + \varepsilon)^2 + \delta^2] [(1 - \varepsilon)^2 + \delta^2]. \quad (12)$$

The polynomial $p(\varepsilon, \delta)$ is too long to be printed here and is of maximum order 16 in ε and δ . It vanishes for $\varepsilon \approx \pm 2$ and $\varepsilon \approx \pm 1$. For $\delta = 1/(\omega_c \tau) = 0.1$, we get the picture shown in Fig. 2. The conductivity is independent of the relative orientation of the polarization of the microwaves [8] and the d.c. current measuring the conductivity. Between $\varepsilon \approx 2$ and $\varepsilon \approx 1$, the contribution of the microwaves is negative; thus increasing intensity I_f of the microwaves diminishes the conductivity until σ becomes zero and one reaches the dissipationless state. Of course, that is outside the scope of our expansion in I_f . Near $\varepsilon = 2$ and $\varepsilon = 1$, there are two points where σ is not modified by the microwaves. The precise form of the conductivity depends on τ (see inset of Fig. 2). From Eq. (12) it is now obvious that the structures in σ are due to resonances at $\varepsilon = \pm 1, \pm 2$. (The behavior at $\varepsilon = 0$ is modified by the ω_f -dependence of I_f .)

After having studied the first order approximation in I_f , we finally analyze the resonances in the N^{th} order in I_f . Vertices (including the vertices corresponding to the external current/vector potential) and lines in a diagram are numbered from 1 to $2N + 2$ following the arrows. Then, the real part of the denominator of the k^{th} Green's function is

$$\epsilon_k = \epsilon - \sum_{j=1}^k (\omega_f \sigma_j + \omega_c s_j). \quad (13)$$

Here, $s_j = \pm 1$ and $\sigma_j = 0, \pm 1$ ($\sigma_j = 0$ at the vertices corresponding to the external current/vector potential) and $\sum_{j=1}^{2N+2} s_j = 0$, $\sum_{j=1}^{2N+2} \sigma_j = 0$. A resonance is to be expected whenever $\epsilon_k = \epsilon_{k'}$. That can occur at $\varepsilon = \pm p/q$ with $p = 1, \dots, N + 1$ and $q = 1, \dots, N$. In lowest order, $N = 1$, we find $\varepsilon = 1, 2$; in next order $N = 2$, $\varepsilon = 1, 2, 3, 1/2, 3/2$.

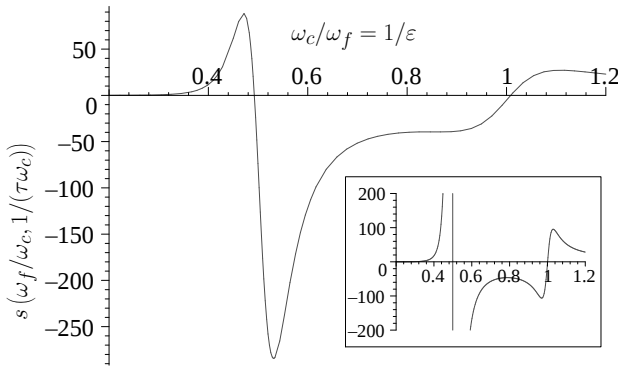


FIG. 2: Contribution of the microwaves to the conductivity relative to the case without microwaves calculated for $\omega_f \tau = 10$ as a function of $1/\varepsilon$. Inset: the same calculation for $\omega_f \tau = 30$.

Note that there is indeed a small structure (admittedly very small) at $1/\varepsilon = 2/3$ in the resistivity at 57 GHz in Fig. 1 of the experiment in Ref. [3]. The order of magnitude of the resonance in σ depends on the degree in the denominator q ; it should be at least $I_f^N \omega_c \tau$.

In this Letter, we have reconsidered the calculation of the conductivity of a quantum Hall system under microwave irradiation. In an expansion in E_f , the amplitude of the microwave field, we analyze the form of the non-linear conductivity analytically. We find that to lowest order the conductivity is independent of the microwave polarization and determine the maximum intensity for which perturbation theory is applicable. We see that the structures in the conductivity are due to resonant scattering of the electrons by the microwaves. We predict minima (or zeros) in the conductivity near arbitrary fractions of the parameter $\varepsilon = \omega_f/\omega_c$. Note that our result, a series of resonances with a width determined by the single particle lifetime τ , is qualitatively different from a damped sinusoidal behavior. In order to verify this picture one should do a systematic study of the photoconductivity with increasing purity of the samples. Then, the observed structure should get sharper. As the intensity of the microwaves increases, more and more minima (zeros) should become visible.

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